

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	370	((tip NEAR10 \$2dent\$5) SAME (medium or substrate or sample)) AND resistance	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 11:33
L2	232	((storage NEAR5 (device or medium)) NEAR15 conduct\$5) AND (resistance or resistivity) AND probe	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 11:18
L3	1149	((369/53.1) or (369/126)).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/09/30 11:32
L4	3566	((73/105) or (250/306) or (250/307)).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/09/30 11:33
L5	0	((tip NEAR10 \$2dent\$5) SAME (medium or substrate or sample)) AND resistance).clms.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 11:34
L6	0	((tip NEAR10 \$2dent\$5) AND (medium or substrate or sample)) AND resistance).clms.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 11:34
L7	0	((tip NEAR10 \$2dent\$5) AND (medium or substrate or sample)) AND (first NEAR3 current) AND (second NEAR3 current) AND (first NEAR3 resistance) AND (second NEAR3 resistance)).clms.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 11:36
L8	0	((tip NEAR10 \$2dent\$5) SAME (medium or substrate or sample)) SAME (first NEAR3 current) SAME (second NEAR3 current) SAME (first NEAR3 resistance) SAME (second NEAR3 resistance)).clms.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 11:36